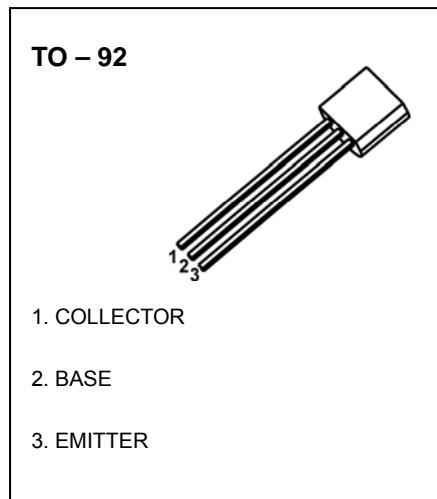


TO-92 Plastic-Encapsulate Transistors

BC556/BC557/BC558 TRANSISTOR (PNP)

FEATURES

- High Voltage
- Complement to BC546,BC547,BC548



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{CBO}	Collector-Base Voltage	BC556	-80	V
		BC557	-50	
		BC558	-30	
V_{CEO}	Collector-Emitter Voltage	BC556	-65	V
		BC557	-45	
		BC558	-30	
V_{EBO}	Emitter-Base Voltage		-5	V
I_C	Collector Current-Continuous		-0.1	A
P_c	Collector Power Dissipation		625	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient		200	°C/W
T_j	Junction Temperature		150	°C
T_{stg}	Storage Temperature		-55~+150	°C

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	BC556	$V_{(\text{BR})\text{CBO}}$	$I_C = -0.1\text{mA}, I_E = 0$	-80		
	BC557			-50		
	BC558			-30		
Collector-emitter breakdown voltage	BC556	$V_{(\text{BR})\text{CEO}}$	$I_C = -2\text{mA}, I_B = 0$	-65		
	BC557			-45		
	BC558			-30		
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$		$I_E = -100\mu\text{A}, I_C = 0$	-5		V
Collector cut-off current	BC556	I_{CBO}	$V_{CB} = -70\text{V}, I_E = 0$		-0.1	μA
	BC557		$V_{CB} = -45\text{V}, I_E = 0$		-0.1	μA
	BC558		$V_{CB} = -25\text{V}, I_E = 0$		-0.1	μA
Collector cut-off current	BC556	I_{CEO}	$V_{CE} = -60\text{V}, I_B = 0$		-0.1	μA
	BC557		$V_{CE} = -40\text{V}, I_B = 0$		-0.1	μA
	BC558		$V_{CE} = -25\text{V}, I_B = 0$		-0.1	μA
Emitter cut-off current	I_{EBO}		$V_{EB} = -5\text{V}, I_C = 0$		-0.1	μA
DC current gain	h_{FE}		$V_{CE} = -5\text{V}, I_C = -2\text{mA}$	120	800	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$			-0.3	V
		$I_C = -100\text{mA}, I_B = -5\text{mA}$			-0.65	V
Base-emitter saturation voltage	$V_{BE(\text{sat})}$	$I_C = -10\text{mA}, I_B = -0.5\text{mA}$			-0.8	V
		$I_C = -100\text{mA}, I_B = -5\text{mA}$			-1	V
Base-emitter voltage	V_{BE}	$V_{CE} = -5\text{V}, I_C = -2\text{mA}$	-0.55		-0.7	V
		$V_{CE} = -5\text{V}, I_C = -10\text{mA}$			-0.82	V
Collector output capacitance	C_{ob}		$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$		6	pF
Transition frequency	BC556	f_T	$V_{CE} = -5\text{V}, I_C = -10\text{mA}, f = 100\text{MHz}$		150	MHz
	BC557				150	MHz
	BC558				150	MHz

CLASSIFICATION of h_{FE}

RANK	A	B	C
RANGE	120-220	180-460	420-800